

Technical Data

Green Products

Data Sheet N1162, Rev. -

124NQ035-1 124NQ040-1 124NQ045-1 SCHOTTKY RECTIFIER

Applications:

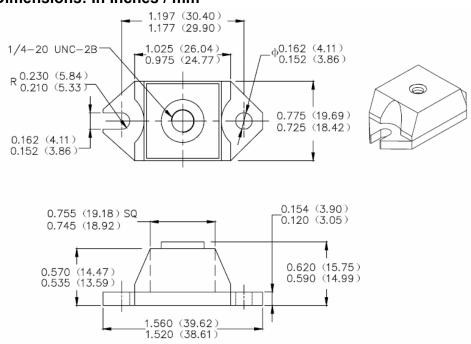
• Switching power supply • Converters • Free-Wheeling diodes • Reverse battery protection

Features:

- 125°C T_J operation
- Unique high power, Half-Pak module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- · Additional testing can be offered upon request



Mechanical Dimensions: In Inches / mm



PRM1-1(HALF PAK Module)

MARKING, MOLDING RESIN

Marking for 124NQ035-1, 1st row SS YYWWL, 2nd row 124NQ035-1 Where YY is the manufacture year WW is the manufacture week code L is the wafer's Lot Number Molding resin

Epoxy resin UL:94V-0

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Maximum Ratings:

Characteristics	Symbol	Condition	Max.		Units
Peak Inverse Voltage	V_{RWM}	-	35 124NQ035-1		V
			40 124NQ040-1		
			45	124NQ045-1	
Max. Average Forward Current	I _{F(AV)}	50% duty cycle @T _C =76°C, rectangular wave form	120		Α
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse		А	
Non-Repetitive Avalanche Energy	E _{AS}	T _J =25℃,I _{AS} =20A,L=0.67mH	135		mJ
Repetitive Avalanche Current	I _{AR}	Current decaying linearly to zero in 1 μ sec Frequency limited by T_J max. V_A =1.5 \times V_R typical	20		А

Electrical Characteristics:

Characteristics	Symbol	Condition	Max	Units
Max. Forward Voltage Drop*	V_{F1}	@ 120A, Pulse, T_J = 25 °C@ 240A, Pulse, T_J = 25 °C	0.54 0.71	V
	V_{F2}	@ 120A, Pulse, T _J = 125 °C @ 240A, Pulse, T _J = 125 °C	0.52 0.71	V
Max. Reverse Current (per	I _{R1}	$@V_R = \text{rated } V_R T_J = 25 ^{\circ}\text{C}$	10	mA
leg) *	I _{R2}	$@V_R = \text{rated } V_R T_J = 125 ^{\circ}\text{C}$	1200	mA
Max. Junction Capacitance (per leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	5200	pF
Typical Series Inductance (per leg)	L _S	Measured lead to lead 5 mm from package body	7.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

Pulse Width < 300µs, Duty Cycle <2%

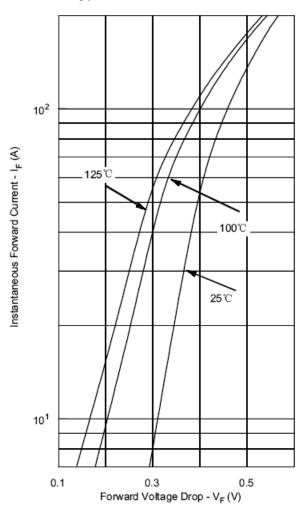
Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specific	Units		
Max. Junction Temperature	T _J	-	-55 to -	°C		
Max. Storage Temperature	T _{stg}	-	-55 to +125		°C	
Maximum Thermal Resistance Junction to Case	$R_{ heta JC}$	DC operation	0.40		°C/W	
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.15		°C/W	
Mounting Torque	Тм	Non-lubricated threads	Mounting Torque	23(min) 29(max)	- Kg-cm	
			Terminal Torque	35(min) 46(max)		
Approximate Weight	wt	-	25.0	g		
Case Style	PRM1-1					

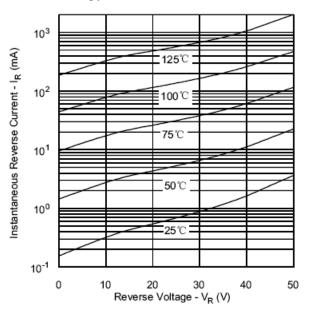
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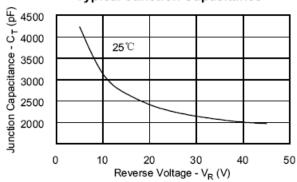
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



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124NQ...-1 SERIES

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